ECE 2030 D	Computer Engineering	Spring 2012
4 problems, 5 pages	Exam Three Solutions	12 April 2012

Problem 1 (3 parts, 30 points)

Memory Systems

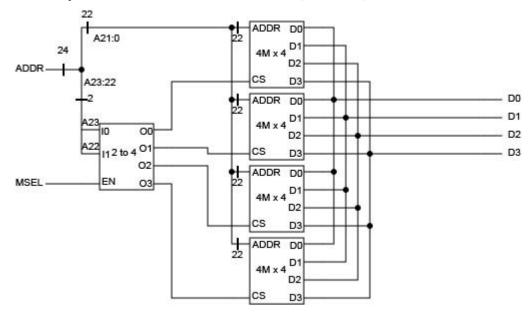
Part A (12 points) Consider a **1 Gbit** DRAM chip organized as **32 million addresses** of **32-bit words**. Assume both the DRAM cell and the DRAM chip are square. The column number and offset concatenate to form the memory address. Using the organization approach discussed in class, answer the following questions about the chip. *Express all answers in decimal (not powers of two)*.

total number of bits in address	log(32M) = log(2 ²⁵) = 25
number of columns	$\sqrt{2^{30}}=2^{15}=32K$
column decoder required (<i>n</i> to <i>m</i>)	15 to 32K
number of words per column	$2^{15}/2^5 = 2^{10} = 1K$
type of mux required (<i>n</i> to <i>m</i>)	1K to 1
number of address lines in column offset	10

Part B (10 points) Consider an **8 Gbyte** memory system with **1 billion addresses** of **64-bit words** using a **32 million** address by **32-bit word** memory DRAM chip.

word address lines for memory system	$log(1B) = log(2^{30}) = 30$
chips needed in one bank	2
banks for memory system	$2^{30}/2^{25} = 2^5 = 32$
memory decoder required (<i>n</i> to <i>m</i>)	5 to 32
DRAM chips required	64

Part C (8 points) Design a **16 million address by 4 bit** memory system with **4M x 4** memory chips. *Label all busses and indicate bit width*. Assume R/W is connected and not shown here. Use a bank decoder if necessary. Be sure to include the address bus, data bus, and MSEL.



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Problem 2 (3 parts, 26 points)

Datapath Elements

Part A (6 points) Suppose the following inputs (in hexadecimal) are applied to the 32-bit barrel shifter used in the datapath. Determine the output (in hexadecimal). Assume the shift amount is drawn from the 16-bit immediate value.

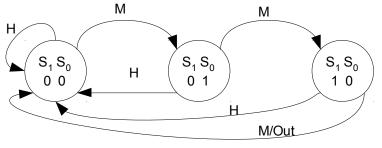
Shift Type	Shift Amount	Input Value	Output Value
arithmetic	0x0008	ABCD12EF	0xFFABCD12
rotate	0xFFF4	DEAF7892	0×F7892DEA
arithmetic	0xFFF0	FACE2537	0×25370000

Part B (8 points) For each bitwise logical function specification below, determine the LF code (in hexadecimal) to correctly program the logical unit.

ХҮ	Out	logical function	LF
0 0	LF ₀	Y + X	E
1 0	LF_1	Х	A
0 1	LF ₂	$X \oplus Y$	6
1 1	LF ₃	$X \cdot Y$	8

Part C (12 points) Given the following state table, draw the corresponding state diagram below.

S ₁	S_0	H/\overline{M}	NS_1	NS_0	Out	S_1	S ₀	H/\overline{M}	NS_1	NS ₀	Out
0	0	0	0	1	0	1	0	0	0	0	1
0	0	1	0	0	0	1	0	1	0	0	0
0	1	0	1	0	0	1	1	0	x	x	x
0	1	1	0	0	0	1	1	1	x	x	x



Give the simplified Boolean expression for computing **Out** in terms of the current state and the input.

 $Out = \underline{S_0M}$

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Problem 3 (3 parts, 26 points)

Microcode

Using the supplied datapath, write microcode fragments to accomplish the following procedures. Express all values, except memory addresses, in hexadecimal notation. Use 'X' when a value is don't cared. For maximum credit, complete the description field. In each part, modify only registers 7 & 8.

Part A (5 points)

 $R_7 = (R_8 - 21)/128$

1 41																	
#	X	Y	Ζ	rwe	im	im va	аи	<u>s</u> /	lu	lf	su	st	ld	st	<u>r/</u>	msel	descrription
					en		en	a	en		en		en	en	\overline{w}		
1	8	×	7	1	1	С	1	1	0	×	0	×	0	0	×	0	R7 ← R8-12
2	7	×	7	1	1	7	0	×	0	×	1	1	0	0	×	0	R7 ← R7>>7
3																	

Part B (15 points) Compute the logical OR of mem[4000] and R_3 and store the result in mem[4004] (that is, mem[4004] gets mem[4000]+R₃, where "+" is "logical or").

1110	'III	100	·] (u	iiut ib	, m	ողեւու	1 800	5 111		000	'] ' IX;	, ייי		' 1	5 10	Bicar	01).
#	X	Y	Ζ	rwe	im en	im va	au en	$\frac{s}{a}$	lu en	lf	su en	st	ld en	st en	$\frac{r}{w}$	msel	description
1	×	×	7	1	1	4000	0	<i>a</i>	1	с	0	×	0	0	×	0	R7 ← 4000
2	7	x	8	1	0	×	0	×	0	×	0	×	1	0	1	1	R8 ← mem[4000]
3	8	3	8	1	0	×	0	×	1	E	0	×	0	0	×	ο	R8 ← R8+R3
4	7	×	7	1	1	4	1	0	0	×	0	×	0	0	×	ο	R7 ← R7+4
5	7	8	×	0	0	×	0	×	0	×	0	×	0	1	0	1	mem[4004] ← R8
6																	

Part C (6 points)

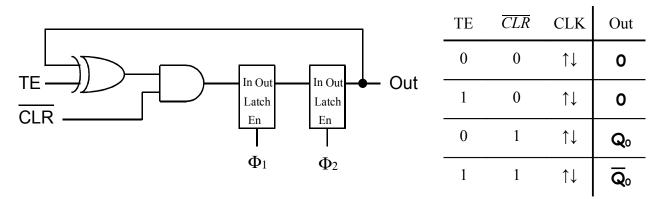
 $R_7 = 15 \cdot R_8$ (multiply R₈ by 15)

I U.																	
#	X	Y	Ζ	rwe	im	im va	аи	<u>s</u> /	lu	lf	su	st	ld	st	<u>r/</u>	msel	description
					en		en	а	en		en		en	en	w		
1	8	×	7	1	1	FFFC	0	×	0	×	1	1	0	0	×	0	R7 ← R8<<4
2	7	8	7	1	0	×	1	1	0	×	0	×	0	0	×	0	R7 ← R7 - R8
3																	
4																	

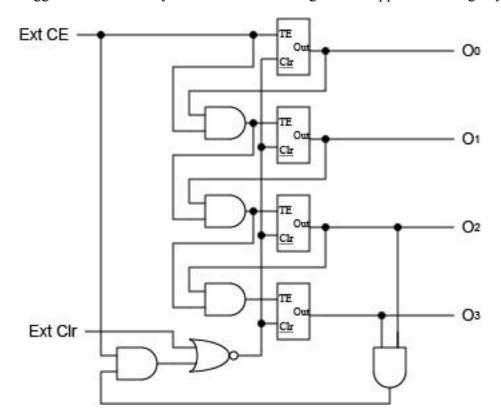
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Problem 4 (2 parts, 18 points)

Part A (8 points) Design a toggle cell using *only transparent latches and basic gates (XOR, AND, OR, NAND, NOR, NOT)*. Use an icon for the transparent latches. Your toggle cell should have an active high toggle enable input TE, and an active low clear input \overline{CLR} , clock inputs Φ_1 and Φ_2 , and an output **Out**. The \overline{CLR} signal has precedence over **TE**. Label all signals. Also complete the behavior table for the toggle cell.



Part B (10 points) Now combine these toggle cells to build a **divide by thirteen** counter. Your counter should have an external clear, external count enable, and four count outputs O_3 , O_2 , O_1 , O_0 . Use any basic gates (AND, OR, NAND, NOR, XOR & NOT) you require. Assume clock inputs to the toggle cells are already connected. Your design must support multi-digit systems.



Counters